NSN 5961-01-321-1921

Semiconductor Device Set - Page 1 of 1



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Inc	losure	Mate	rial:

Plastic all light emitting diode

Overall Length:

0.400 inches all light emitting diode

Terminal Length:

0.125 inches all light emitting diode

Overall Height:

0.245 inches all light emitting diode

Overall Width:

0.150 inches all light emitting diode

Lens Transparency:

Transparent all light emitting diode

Component Function Relationship:

Matched

Component Name And Quantity:

4 light emitting diode

Mounting Method:

Terminal all light emitting diode

Semiconductor Material:

Gallium arsenide phosphide all light emitting diode

Voltage Rating In Volts Per Characteristic:

2.6 forward voltage, dc all light emitting diode

Current Rating Per Characteristic:

25.00 milliamperes source cutoff current preset all light emitting diode

Power Rating Per Characteristic:

135.0 milliwatts small-signal input power, common-collector preset all light emitting diode

Color Tone Produced Per Source:

Red lens all light emitting diode

Luminous Intensity:

6.0 millicandela all light emitting diode

Maximum Operating Tempurature Per Measurement Point:

85.0 degrees celsius junction all light emitting diode

Terminal Type And Quantity:

4 pin all light emitting diode

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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